Sheet	1	of	1
SHEEL	1	OI	1

Substitute from PTO-1449

U.S. Department of Commerce Patent and Trademark Office

Information Disclosure Statement

All6 3 1 2005

by Applicant

Several sheets if necessary)

Attorney's Docket No. 16459-011001

Application No. 10/724,015

Applicant

Alexei A. Erchak

Filing Date

November 26, 2003

Several Statement

November 26, 2003

Inne	U.S. Patent Documents						
Examiner Initial	Desig. ID	Document Number	Publication Date	Patentee	Class	Subclass	Filing Date If Appropriate
M	AA	5,132,751	July 21, 1992	Shibata, et al.			
	AB			·			
	AC						·
	AD						
	AE		:				
	AF						
	AG						
	AH						
	AI						
	AJ						
	AK						

L	Foreig	n Patent Doo	uments or Pu	Foreign Patent Documents or Published Foreign Patent Applications							
Examiner	Desig.	Document	Publication	Country or			Translation				
Initial	ID	Number	Date	Patent Office	Class	Subclass	Yes	No			
	AL										
	AM										
	AN					_					
	AO										
	AP					_					

	Other Documents (include Author, Title, Date, and Place of Publication)							
Examiner	Desig.							
Initial	ID	Document						
W	AQ	A. Köck et al., "Novel surface emitting GaAs/AlGaAs laser diodes based on surface mode emission," Appl. Phys. Lett. 63 (9), 30 August 1993, pages 1164-1166						
M	AR	A. Köck et al., "Strongly directional emission from AlGaAs/GaAs light-emitting diodes," Appl. Phys. Lett. 57 (22), 26 November 1990, pages 2327-2329						
	AS							
	AT							

Examiner Signature	Date Considered 9/12/07
EXAMINER: Initials citation considered. Draw line through citation in	if not in conformance and not considered. Include copy of this form with

				· —— · · ·
0	Bussilote Form PTO-1449 (Modified)	U.S. Department of Commerce Patent and Trademark Office	Attorney's Docket No. 16459-011001	Application No. 10/724,015
AU6	10 3 7000 111	sclosure Statement Applicant	Applicant Alexei A. Erchak	
EREC.	(Use several (37 CF6581.98(b))	sheets if necessary)	Filing Date November 26, 2003	Group Art Unit 2879

			U.S. Patent	Documents		·	
Examiner Initial	Desig. ID	Document Number	Publication Date	Patentee	Class	Subclass	Filing Date If Appropriate
M	AA	5,126,231	June 30, 1992	Levy			
1	AB	6,778,746	August 17, 2004	Charlton, et al.			
	AC	6,742,907	June 1, 2004	Funamoto, et al.			
	AD	2004/0110856	June 10, 2004	Young, Jung Gun et al.			
	AE	2004/0144985	July 29, 2004	Zhang, Zhibo, et al.			
	AF	2004/0207310	October 21, 2004	Erchak et al.			
	AG	2004/0207319	October 21, 2004	Erchak et al.			
	AH	2004/0207323	October 21, 2004	Erchak et al.			
	ΑI	2004-0206962	October 21, 2004	Erchak et al.			
	AJ	2004-0206971	October 21, 2004	Erchak et al.			
	AK	2004-0207320	October 21, 2004	Erchak			
	AL	2004-0259279	December 23, 2004	Erchak et al.			
	AM	2004-0259285	December 23, 2004	Erchak et al.			
	AN	2005/0051785	March 10, 2005	Erchak et al.			
	AO	2005/0051787	March 10, 2005	Erchak et al.			
	AP	2005/0087757	April 28, 2005	Erchak et al.			
	AQ	2005-0040424	February 24, 2005	Erchak et al.			
	AR	2005-0059178	March 17, 2005	Erchak et al.			
	AS	2005-0059179	March 17, 2005	Erchak et al.			
	AT	2005-0087754	April 28, 2005	Erchak			
	AU	2005-0127375	June 16, 2005	Erchak et al.			
	AV	3,293,513	August 8, 1962	J.R. Biard et al.			
	AW	3,922,706	November 25, 1975	Kaiser			
	AX	4,864,370	September 5, 1989	Gaw et al.			
	AY	5,126,231	June 30, 1992	Levy		-	
V	AZ	6,071,795	06/06/00	Cheung et al.			

Examiner Signature	Date Considered 9/12/07
EXAMINER: Initials citation considered. Draw line through citation if no	t in conformance and not considered. Include copy of this form with
next communication to applicant	

Substitute Form PTO-1449 (Modified)	U.S. Department of Commerce Patent and Trademark Office	Attomey's Docket No. 16459-011001	Application No. 10/724,015	
by A	closure Statement	Applicant Alexei A. Erchak		
(Use several st	neets if necessary)	Filing Date November 26, 2003	Group Art Unit 2879	

			U.S. Patent	Documents			
Examiner Initial	Desig. ID	Document Number	Publication Date	Patentee	Class	Subclass	Filing Date If Appropriate
The	AAA	6,778,746	August 17, 2004	Charlton, et al.			
N	ABB	6,849,558	February 1, 2005	Schaper			
W	ACC	6,307,218	October 23, 2001	Steigerwald et al.			
4/2	ADD	5,600,483	February, 1997	Fan et al.			

	Foreign Patent Documents or Published Foreign Patent Applications							
Examiner	Desig.	Document	Publication	Country or			Translation	
Initial	ID	Number	Date	Patent Office	Class	Subclass	Yes	No
	AEE							
	AFF							
	AGG							
	АНН							
	AII						<del></del>	

	Other Documents (include Author, Title, Date, and Place of Publication)							
Examiner	Desig.							
Initial	ID	Document						
	AJJ							
	AKK							
	ALL							
	AMM							

Examiner Signature	Date Considered /
Media	9/12/05
EXAMINER: Initials citation considered. Draw line through citation if no	ot in conformance and not considered. Include copy of this form with
next communication to applicant.	•

Substitute Form PTO-1449

U.S. Department of Commerce Patent and Trademark Office Attorney's Docket No. 16459-011001

Application No. 10/724,015

Applicant **Information Disclosure Statement** 

by Applicant (Use several sheets if necessary)

Alexei A. Erchak Filing Date

November 26, 2003

Group Art Unit 2879

(37 CFR §1.98(b))

			U.S. Pate	ent Documents			
Examiner Initial	Desig. ID	Document Number	Publication Date	Patentee	Class	Subclass	Filing Date If Appropriate
M	AA	6,831,302	12/14/04	Erchack et al.		_	
1	AB	6,504,180	1/7/03	Heremans, et al.	1		
	AC	6,690,268	2/10,/04	Schofield, et al.			
	AD	6,642,618	11/4/03	Yagi, et al.			
	AE	6,784,027	8/31/04	Streubel, et al.			
	AF	6,847,057	1/25/05	Gardner, et al.			
	AG	6,072,628	6/6/00	Sarayeddine .		•	
	AH	6,122,103	9/19/00	Perkins, et al.			
	AI	6,288,840	9/11/01	Perkins, et al.			
	AJ	6,574,383	6/3/03	Erchak, et al.			
	AK	6,504,180	1/7/03	Heremans, et al.			
	AL	6,690,268	2/10/04	Schofield, et al.			
	AM	5,162,878	11/10/92	Sasagawa, et al.			
	AN	6,828,597	12/07/04	Wegleiter, et al.			
	AO	5,814,839	9/29/98	Hosoba			
	AP	5,491,350	2/13/96	Unno, et al.			
	AQ	6,303,405	10/16/01	Yoshida, et al.			
	AR	2002/0110172	8/15/02	Hasnain, Ghulam, et al.			
	AS	6,222,207	4/24/01	Carter-Coman, et al.			-
	AT	6,593,160	7/15/03	Carter-Coman, et al.			
	AU	6,573,537	6/3/03 <sup>°</sup>	Steigerwald, et al.			
	AV	6,465,808	10/15/02	Lin			
	AW	2003-0143772	7/31/03	Chen, Tzer-Perng			
	AX	6,762,069	7/13/04	Huang, et al.			
	AY	6,649,437	11/18/03	Yang, et al.			
	AZ	6,740,906	5/25/04	Slater, Jr., et al.			
W	AAA	6,791,119	9/14/04	Slater, Jr., et al.			

Examiner Signature	MAZI		Date Considered	12/05
EXAMINER: Initials	citation considered. Dr	aw line through citation if no	t in conformance and not con	sidered. Include copy of this form with

next communication to applicant.



om PTO-1449

U.S. Department of Commerce Patent and Trademark Office

Attorney's Docket No. 16459-011001

Filing Date

Application No. 10/724,015

Applicant **Information Disclosure Statement** 

by Applicant (Use several sheets if necessary)

Alexei A. Erchak

November 26, 2003

Group Art Unit 2879

(37 CFR §1.98(b))

	U.S. Patent Documents							
Examiner Initial	Desig. ID	Document Number	Publication Date	Patentee	Class	Subclass	Filing Date If Appropriate	
M	ABB	6,794,684	9/21/04	Slater, Jr., et al.			4	
) .	ACC	6,825,502	11/30/04	Okazaki, et al.				
	ADD	2004-0182914	9/23/04	Venugopalan, Hari S.				
V	AEE	2005-0019971	1/27/05	Slater, David B. Jr.				

	Foreign Patent Documents or Published Foreign Patent Applications								
Examiner	Desig.	Document	Publication	Country or			Trans	slation	
Initial	ID	Number	Date	Patent Office	Class	Subclass	Yes	No	
W	AFF	02/071450 A2		wo					
	AGG								
	АНН								
	AII		•						
	AJJ								

	Other Documents (include Author, Title, Date, and Place of Publication)						
Examiner	Desig.	X					
Initial	ID	. Document					
M	AKK	Wendt et al. "Nanofabrication of photonic lattice structures in GaAs/AlGaAs," J. Vac. Sci. Technol. B 11 (6), Nov/Dec 1993, pages 2637-2640					
M	ALL	Gourley et al. "Optical properties of two-dimensional photonic lattices fabricated as honeycomb nanostructures in compound semiconductors," Appl. Phys. Lett. 64 (6), 7 February 1994, pages 687-689					
	AMM						
,	ANN						

Examiner Signature	Date Considered 9/12/05
EXAMINER: Initials citation considered. Draw line through citation if no	t in conformance and not considered. Include conv of this form with

next communication to applicant.

Sheet 1 of 1	
--------------	--

Substitute Form PTO-1449	U.S. Department of Commerce Patent and Trademark Office	Attorney's Docket No. 16459-011001	Application No. 10/724,015	
a 2005 by Ar	closure Statement	Applicant Alexei A. Erchak		
(Use several sh	eets if necessary)	Filing Date November 26, 2003	Group Art Unit 2879	

			U.S. Patent D	ocuments			
Examiner Initial	Desig. ID	Document Number	Publication Date	Patentee	Class	Subclass	Filing Date If Appropriate
M	AA	5,834,331	November 10, 1998	Razeghi			
1	AB	6,426,515	July 30, 2002	Ishikawa			
	AC	2003/0222263	December 4, 2003	Choi			
<b>V</b>	AD	6,091,085	July 18, 2000	Lester			
	AE						
	AF						
	AG						
	AH			·			
	AI						
	AJ						
	AK						

	Foreign Patent Documents or Published Foreign Patent Applications								
Examiner	Desig.	Document	Publication	Country or			Trans	lation	
Initial	ID	Number	Date	Patent Office	Class	Subclass	Yes	No	
	AL								
	AM	-							
	AN								
	AO			,					
	AP								

	Other Documents (include Author, Title, Date, and Place of Publication)							
Examiner Initial	Desig. ID	Document						
	AQ							
	AR							
	AS							
	ΑT							

Examiner Signature	Date Considered / /
a de la	1 9/12/05
1000	1118107
EXAMINER: Initials citation considered. Draw line through citation	if not in conformance and not considered. Include copy of this form with
next communication to applicant	• • •



Form PTO-1449

U.S. Department of Commerce Patent and Trademark Office Attorney's Docket No. 16459-011001

Application No. 10/724,015

Information Disclosure Statement

by Applicant (Use several sheets if necessary)

5,793,062

AS

08/11/98

Alexei A. Erchak

November 26, 2003

Filing Date

Applicant

Group Art Unit 2879

(37 CFR §1.98(b))

**U.S. Patent Documents** Filing Date **Publication** Desig. Document Examiner If Appropriate Patentee Class Subclass Initial ID Number Date MIN 10/25/94 Hunter et al. AA 5,359,345 05/20/97 Negley et al. AB 5,631,190 03/03/98 Hunter et al. AC 5,724,062 07/14/98 Krames et al. AD 5,799,924 ΑE 5,955,749 09/21/99 Joannopoulos et al. 06/06/00 Cheung et al. AF 6,071,795 6,420,242 07/16/02 Cheung et al. AG 05/06/03 Kelly et al. AH 6,559,075 6,410,942 06/25/02 Thibeault et al. ΑI 12/02/03 Thibeault et al. ΑJ 6,657,236 Krames et al. 2003/0141507 07/31/03 AK 5,633,527 05/27/1997 Lear 02/06/95 AL 5,363,009 08/10/92 AM 11/8/1994 Monto 5,073,041 Rastani 11/13/90 AN 12/17/1991 5,426,657 06/20/1995 Vakhsoori 05/27/94 AO 02/19/98 6,091,085 07/18/00 Lester AP 6,469,324 10/22/02 Wang, Tien Yang AQ AR 6,287,882 09/11/01 Chang et al.

Foreign Patent Documents or Published Foreign Patent Applications								
Examiner	Desig.	Document	Publication	Country or			Trans	slation
Initial	ID	Number	Date	Patent Office	Class	Subclass	Yes	No
M	AT	WO 98/14986	04/09/98	PCT				

Kish et al.

Other Documents (include Author, Title, Date, and Place of Publication)			
Examiner	Desig.		
Initial	·ID	Document	
m	AU	W.S. Wong et al. "Damage-free separation of GaN thin films from sapphire substrates", Appl. Phys. Lett. 72 (5), February 2, 1998, pages 599-601	

Examiner Signature	Madde	Date Considered 9/12/07		
EXAMINER: Initials citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.				
		Substitute Disclosure Form (PTO-14	49)	

The PTO did not receive the following listed Items(s) FOR WO 98/1498C



PTO-1449

U.S. Department of Commerce Patent and Trademark Office Attorney's Docket No. 16459-011001

Application No. 10/724,015

Information Disclosure Statement by Applicant (Use several sheets if necessary)

Alexei A. Erchak

Filing Date November 26, 2003

Applicant

Group Art Unit 2879

(37 CFR §1.98(b))

	Other D	ocuments (include Author, Title, Date, and Place of Publication)		
Examiner	Desig.			
Initial	ID	Document		
ms	ΑV	M.K. Kelly et al. "Optical process for liftoff of Group III-nitride films", Physica Status Solidi; Rap Research Note, November 28, 1996, 2 pages.		
	AW	A. A. Erchak et al. "Enhanced coupling to vertical radiation using a two-dimensional photonic crystal in a semiconductor light-emitting diode", Appl. Phys. Lett. (78 (5), January 29, 2001, pages 563-565		
	AX	P.L. Gourley et al. "Optical properties of two-dimensional photonic lattices fabricated as honeycomb nanostructures in compound semiconductors", Appl. Phys. Lett. 64(6), February 7, 1994, pages 687-689		
	AY	P.L. Gourley et al. "Optical Bloch waves in a semiconductor photonic lattice", Appl. Phys. Lett. 60 (22), June 1, 1992, pages 2714-2716		
	AZ	J.R. Wendt et al. "Nanofabrication of photonic lattice structures in GaAs/AIGaAs", J.Vac. Sci. Technol. B 11(6), November/December 1993, pages 2637-2640		
	AAA	M. Krames et al "Introduction to the Issue on High-Efficiency Light-Emitting Diodes", IEEE Journal on selected topic in quantum electronics, Vol. 8, No. 2 March/April 2002, pages 185-188		
	ABB	K. Streubel et al "High Brightness AlGaInP Light-Emitting Diodes", IEEE Journal on selected topic in quantum electronics, Vol. 8, No. 2, March/April 2002, pages 321-332		
	ACC	M. Okai et al. "Novel method to fabricate corrugation for a λ/4-shifted distributed feedback laser using a granting photomask", Appl. Phys. Lett. 55(5), July 31, 1989, pages 415-417		
	ADD	T.L. Koch et al. "1.55-µ InGaAsP distributed feedback vapor phase transported buried heterostructure lasers", Appl. Phys. Lett. 47 (1), July 1, 1985, pages 12-14		
	AEE	W.T. Tsang'et al. "Semiconductor distributed feedback lasers with quantum well or superlattice grating for index or gain-coupled optical feedback", Appl. Phys. Lett. 60 (21), May 25 1992, pages 258-2582		
	AFF	M. Zelsmann et al. "Seventy-fold enhancement of light extraction from a defectless photonic crystal made on silicon-on-insulator", Appl. Phys. Lett. 83 (13), September 29, 2003, pages 2542-2544		
	AGG	M. Rattier et al. "Omnidirectional and compact guided light extraction from Archimedean photonic lattices", Appl. Phys. Lett. 83 (7), August 18, 2003, pages 1283-1285		
	АНН	YJ. Lee et al. "A high-extraction-efficiency nanopatterned organic light-emitting diode", Appl. Phys. Lett. 82(21), May 26, 2003, pages 3779-3781		
	AII	I. Schnitzer et al. "30% external quantum efficiency from surface textured, thin-film light-emitting diodes", Appl. Phys. Lett. 63 (18), October 18, 1993, pages 2174-2176		
	· AJJ	M. Boroditsky et al. "Light extraction from optically pumped light-emitting diode by thin-slab photonic crystals", Appl. Phys. Lett. 75 (8), August 23, 1999, pages 1036-1038		
	AKK	L. Chen et al. "Fabrication of 50-100 nm Patterned InGaN Blue Light Emitting Heterostructures", Phys. Stat. Sol. (a), 188 (1), 2001, pages 135-138.		
	ALL	I. Bulu et al. "Highly directive radiation from sources embedded inside photonic crystals", Appl. Phys. Lett. 83 (16), October 20, 2003, pages 3263-3265		
	AMM	T. N. Oder et al. "III-nitride photonic crystals", Appl. Phys. Lett. 83 (6), August 11, 2003, pages 1231-1233		
Ą	ANN	M.K. Kelly et al. "Optical patterning of GaN films", Appl. Phys. Lett 68 (12), September 16, 1996, pages 1749-1751		

	<i></i>		
Examiner Signature		Date Considered	··· / ,
Examiner Signature Making			_ / /
~////d/8109	_	$\mathcal{A}$	7/12/05
(Wy) ~		97	111610
EXAMINED: Initials citation considered	Draw line through citation if no	t in conformance and	nd not considered. Include copy of this form with
LYVIIII 4517. Illingis amuoli consideres.	. Dien mie andegn dielen i no		veri

next communication to applicant.